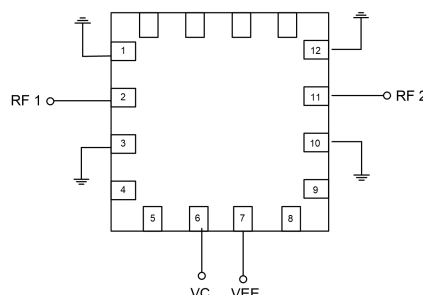


## GaAs MMIC 1 Digital Attenuator Chip, DC-20GHz

### Performance characteristics

Frequency range: DC-20GHz  
 Insertion loss: 2.2dB@20GHz  
 Attenuation range: 20dB  
 Bit count: 1  
 Attenuation accuracy: 1dB Additional  
 phase shift: 3°  
 50Ohm input/output  
 Chip size: QFN 3X3

### Functional Block Diagram



### Product Introduction

GDA-0020-1C-20-PD-CQ3 is a GaAs MMIC 1-bit CNC attenuator chip, with a frequency range of DC~20GHz and insertion loss of 2.2dB. The integrated driver inside the chip is powered by -5V and controlled by 0/+5V (compatible with +3.3V). The amplifier adopts a 3X3mm surface mount lead-free ceramic tube shell, and the surface of the pin solder pads is treated with a gold plating process, suitable for reflow soldering installation process.

### Usage restriction parameter<sup>1</sup>

Control voltage range	-0.5V~+5.5V
Power supply voltage	-6V
Maximum input power	+24dBm
Working temperature	-55 ~ +85°C
Storage temperature	-65 ~ +150°C

**【1】** Exceeding any of the above maximum limits may result in permanent damage.

### Electrical parameters(Ta=+25° C)

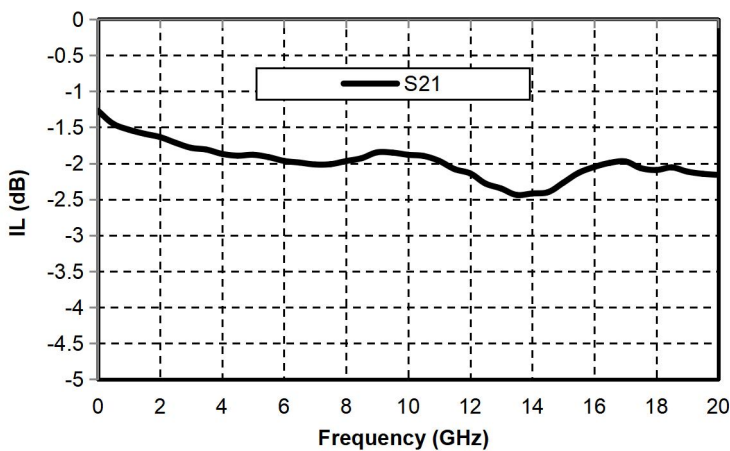
Index	Minimum	Typical value	Maximum value	Unit
Frequency range	DC~20			GHz
Insertion loss	-	2.2	-	dB
Attenuation range	20			dB
Attenuation number	1			bite
Attenuation accuracy (all frequency bands)	1.0			dB
Phase fluctuation (full frequency band)	3.0			degree
Input return loss	-	18	-	dB

Output Return Loss	-	18	-	dB
Switching speed	-	20	-	ns
P-1dB @>1GHz	-	23	-	dBm
Power supply voltage	-	-5	-	V
Control voltage	0	-	+5	V
Current	-	2	-	mA

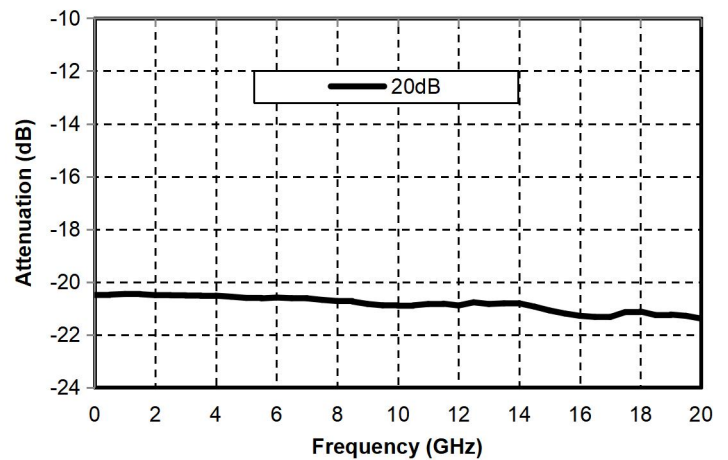
## GaAs MMIC 1 Digital Attenuator Chip, DC-20GHz

### Main indicator testing curve

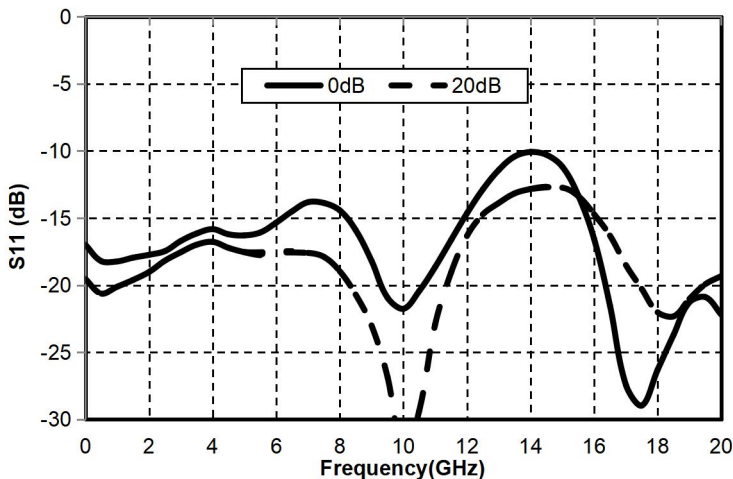
Insertion loss vs. frequency



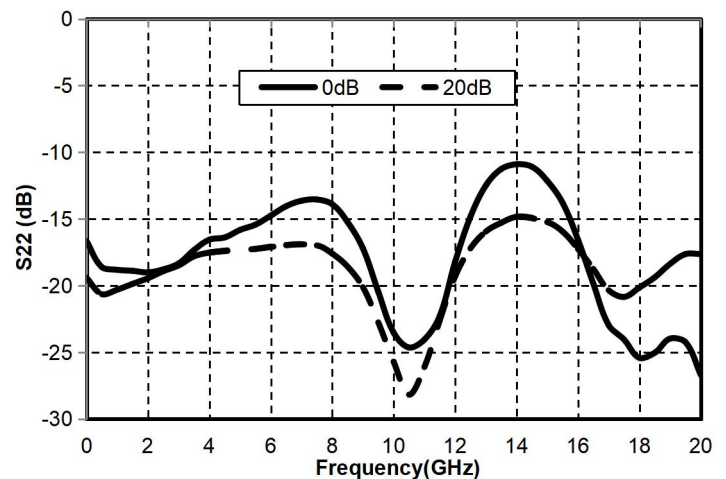
Reference attenuation state vs. frequency



Input Echo vs. Frequency

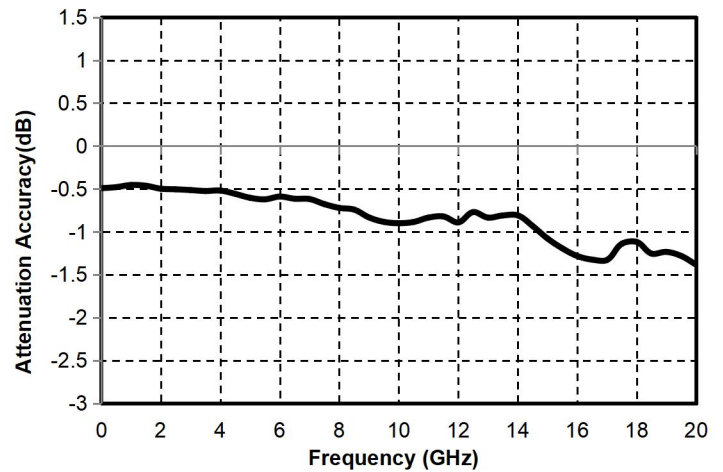
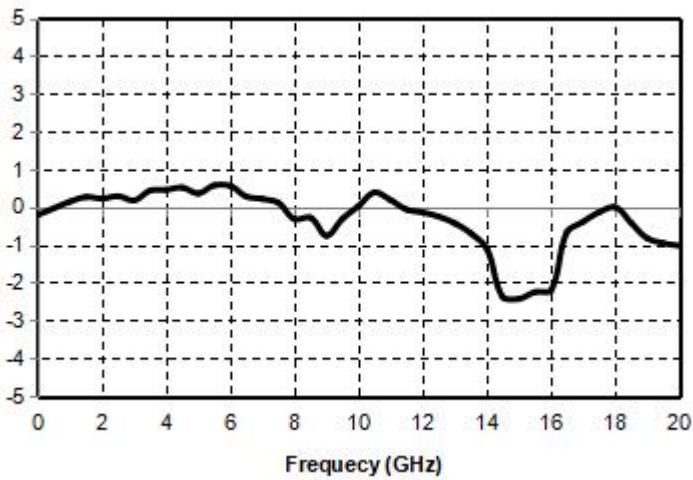


Output Echo vs. Frequency



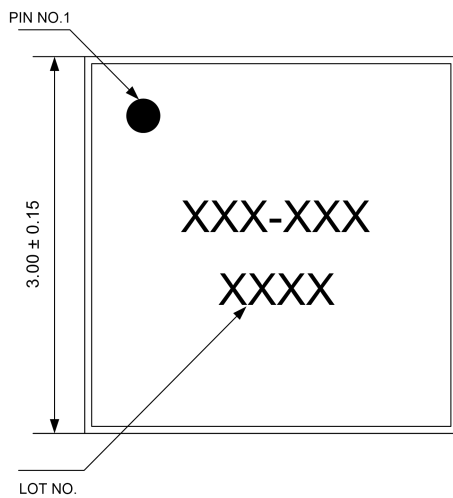
Attenuation additional phase shift vs. frequency

Attenuation accuracy vs. frequency

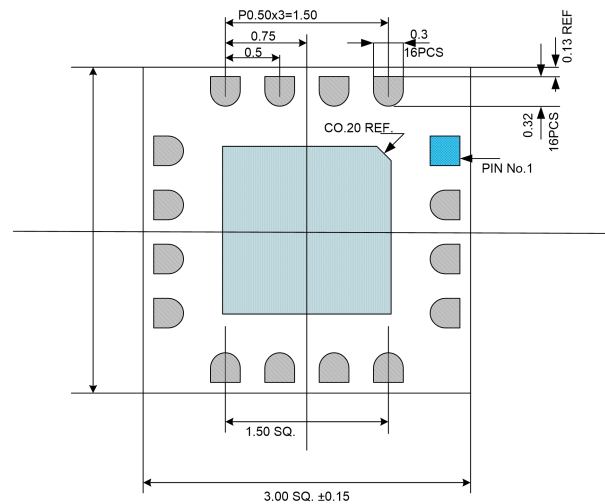


## GaAs MMIC 1 Digital Attenuator Chip, DC-20GHz

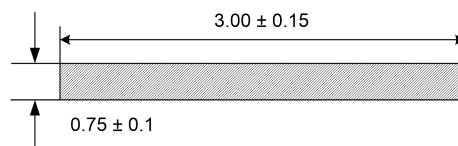
### External structure



vertical view



Top view



Side view

The units in the figure are all millimeters, with an unspecified tolerance of  $\pm 0.15$ mm

## Pin Definition

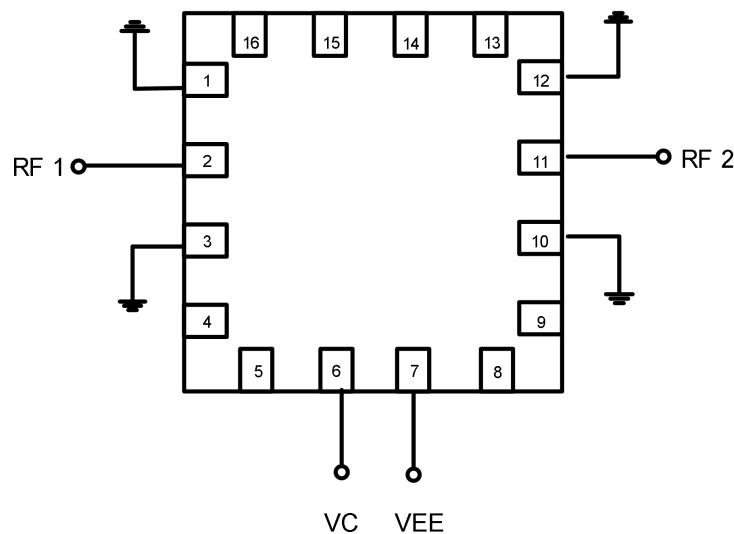
Bond point number	Functional symbols	Function Description
2	RFIN	The RF signal input terminal is externally connected to a 50 ohm circuit and requires an additional broadband DC isolation capacitor
11	RFOUT	The RF signal output terminal is externally connected to a 50 ohm circuit and requires an additional broadband DC isolation capacitor
6	VC	Attenuation control pads, see truth table for attenuation control details
7	VEE	Power supply terminal
1、3、10、12	GND	The pins need to be well grounded with RF and DC
Chip bottom	GND	The bottom of the chip needs to be well grounded with RF and DC
other	NC	No welding required, can be grounded

## Truth table

supply voltage	control input	Attenuation state
VEE	VC	/
-5V	0V	Initial state N=0: attenuation amount is 0
-5V	+5V	Attenuation state N=1: Attenuation amount is 20dB

## GaAs MMIC 1 Digital Attenuator Chip, DC-20GHz

## Recommended circuit



## Precautions for use

- Sealing material: Ceramic material that meets ROHS specifications
- Lead surface coating: gold, with a gold layer thickness greater than 0.3um MIN
- Maximum reflow soldering peak temperature: 260 °C